

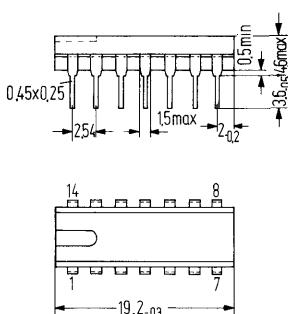
An economical and universal operational amplifier which by its excellent performance qualities is well suited for a wide range of applications such as measurement- and servo-systems, automobile electronics, AF-circuits, analog computers etc. The low input current of this amplifier is particularly advantageous in measurement- and servo system applications. In addition to a high gain, low offset voltage, small temperature- and supply voltage-dependence, the amplifier features

- High input resistance
- Wide common-mode range
- Large supply voltage range
- Large control range
- High output current

Type	Ordering codes
TBB 4331 A	Q67000-A1166
TBE 4335 A	Q67000-A1167

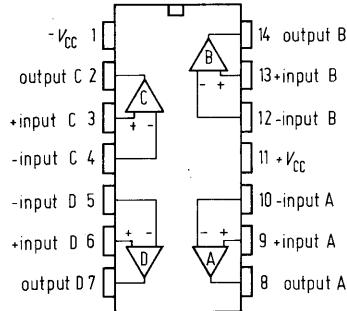
For single amplifier performance, see TCA 311 data sheet.

Package outlines

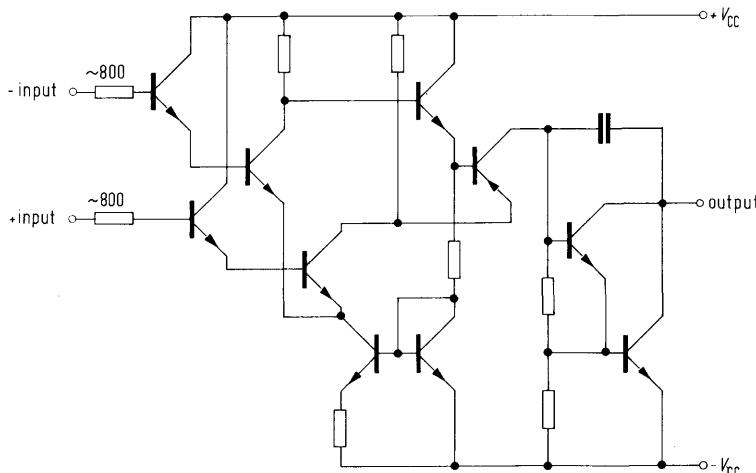


Plastic plug-in package, 14 pins
20 A 14 DIN 41866 (TO-116)
Weight approx. 1.1 g
Dimensions in mm

Pin connection



Equivalent circuit



Maximum ratings

		TBB 4331 A TBE 4335 A	
Supply voltage	V_{CC}	±15	V
Output current	I_g	70	mA
Differential input voltage $V_{CC} = \pm 13$ to ± 15 V	V_{IP}	±13	V
Differential input voltage $V_{CC} = \pm 2$ to ± 13 V	V_{ID}	± V_{CC}	
Junction temperature	T_j	150	°C
Storage temperature	T_s	-55 to +125	°C
Thermal resistance: System-ambient air	R_{thSamb}	140	k/W

Range of operation

Supply voltage	V_{CC}	±2 to ±15	V
Ambient temperature in operation TBB 4331 A	T_{amb}	0 to +70	°C
TBE 4335 A	T_{amb}	-25 to +85	°C

Operating characteristics

($V_{CC} = \pm 15$ V, $T_{amb} = 25^\circ\text{C}$)

		TBB 4331 A TBE 4335 A			
		min	typ	max	
Supply current	I_{CC}		1	3	mA
Input offset voltage ($R_G = 50 \Omega$)	V_{IO}	-15		15	mV
Input offset current	I_{IO}	-25		25	nA
Input current	I_i		30	50	nA
Output voltage ($R_L = 2 \text{ k}\Omega$)	V_{QPP}	14.9		-14	V
($R_L = 620 \Omega$)	V_{QPP}	14.9		-12.5	V
Input impedance ($f = 1 \text{ kHz}$)	Z_i		3		MΩ
Open-loop voltage gain ($R_L = 2 \text{ k}\Omega$, $f = 100 \text{ Hz}$)	G_V	75	80		dB
($R_L = 10 \text{ k}\Omega$, $f = 100 \text{ Hz}$)	G_V		85		dB
Output saturation voltage ($I_o = 10 \text{ mA}$)	V_{QSAT}			1	V
Output leakage current	I_{OLK}		1	10	μA
Input common-mode range ($R_L = 2 \text{ k}\Omega$)	V_{ICM}	12	±13.5	-12	V
Common-mode rejection ratio ($R_L = 2 \text{ k}\Omega$)	$CMRR$	65	79		dB
Sensitivity to supply voltage variation ($G_V = 100$)	$\frac{\Delta V_{IO}}{\Delta V_{CC}}$		25	100	μV/V
Temp.-coefficient of V_{IO} ($R_G = 50 \Omega$)	α_{VIO}		12		μV/K
Temp.-coefficient of I_{IO} ($R_G = 50 \Omega$)	α_{IIO}		50		pA/K
$V_{CC} = \pm 5$ V					
Supply current	I_{CC}		1		mA
Input offset voltage	V_{IO}	-15		15	mV
Input offset current	I_{IO}	-25	±10	25	nA
Input current	I_i		30	50	nA
Open-loop voltage gain ($R_L = 2 \text{ k}\Omega$, $f = 1 \text{ kHz}$)	G_V	70			dB
Output voltage ($R_L = 2 \text{ k}\Omega$)	V_{QPP}	4.9		-4	V